

Enhanced ultrafast power diode Rev.02 - 21 February 2024

Product data sheet

## 1. General description

Enhanced ultrafast power diode in a SOT404 (D2PAK) surface-mountable plastic package.

#### 2. Features and benefits

- High thermal cycling performance
- Low on-state losses
- Low thermal resistance
- Soft recovery characteristic
- Surface-mountable package

### 3. Applications

- Dual Mode (DCM and CCM) PFC
- Power Factor Correction (PFC) for Interleaved Topology

### 4. Quick reference data

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Symbol	Parameter	Conditions	Mir	n Typ	Max	Unit
V <sub>R</sub>	reverse voltage	DC	-	-	600	V
I <sub>F(AV)</sub>	average forward current	$\delta = 0.5$ ; T <sub>mb</sub> $\leq$ 115 °C; SQW; <u>Fig. 1</u> ; <u>Fig. 2</u>	-	-	9	A
I <sub>FRM</sub>	repetitive peak forward current	$\delta$ = 0.5 ; $t_{p}$ = 25 µs; $T_{mb}$ ≤ 115 °C; SQW	-	-	18	A
I <sub>FSM</sub>	non-repetitive peak	t <sub>p</sub> = 10 ms; T <sub>j(init)</sub> = 25 °C; SIN; <u>Fig. 3</u>	-	-	91	А
	forward current	t <sub>p</sub> = 8.3 ms; T <sub>j(init)</sub> = 25 °C; SIN; <u>Fig. 3</u>	-	-	100	А
Static chara	acteristics					
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 8 A; T <sub>j</sub> = 25 °C; <u>Fig. 5</u>	-	1.45	1.9	V
		I <sub>F</sub> = 8 A; T <sub>j</sub> = 150 °C; <u>Fig. 5</u>	-	1.25	1.7	V
Dynamic ch	naracteristics	·			·	
t <sub>rr</sub>	reverse recovery time	I <sub>F</sub> = 1 A; V <sub>R</sub> = 30 V; dI <sub>F</sub> /dt = 100 A/μs; T <sub>i</sub> = 25 °C; <u>Fig. 6</u>	-	17.5	35	ns

# 5. Pinning information

Table 2. P	inning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	not connected		
2	К	cathode		К — <del>С —</del> А 001ааа020
3	А	anode	<u> </u> <u></u>	
mb	К	mounting base; connected to cathode	$ \begin{bmatrix} & & \\ &$	

[1] it is not possible to make connection to Pin 2 of the TO263 package.

# 6. Ordering information

#### Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
BYV29FB-600	TO263	BYV29FB-600,118	Reel	800	TO263N (N)	26-Sep-2016
					TO263P (P)	12-Jun-2023

### 7. Marking

Table 4. Marking codes					
Marking codes					
Assembly factory: N	Assembly factory: P				
BAV29FB 600 PINYYY YY	BYV29FB 600 PJPxxxx xx				
	Assembly factory: N BAV29FB				

### 7. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>RRM</sub>	repetitive peak reverse voltage		-	600	V
V <sub>RWM</sub>	crest working reverse voltage		-	600	V
V <sub>R</sub>	reverse voltage	DC	-	600	V
I <sub>F(AV)</sub>	average forward current	δ = 0.5 ;T <sub>mb</sub> ≤ 115 °C; SQW; <u>Fig. 1</u> ; <u>Fig. 2</u>	-	9	A
I <sub>FRM</sub>	repetitive peak forward current	$\delta$ = 0.5 ; t <sub>p</sub> = 25 µs; T <sub>mb</sub> ≤ 115 °C; SQW	-	18	A
I <sub>FSM</sub>	non-repetitive peak	t <sub>p</sub> = 10 ms; T <sub>j(init)</sub> = 25 °C; SIN; <u>Fig. 3</u>	-	91	А
	forward current	t <sub>p</sub> = 8.3 ms; T <sub>j(init)</sub> = 25 °C; SIN; <u>Fig. 3</u>	-	100	А
T <sub>stg</sub>	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C

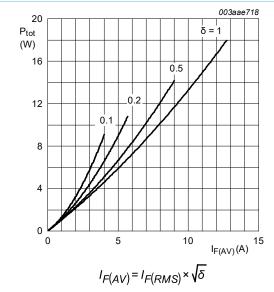


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

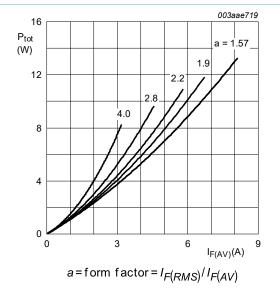
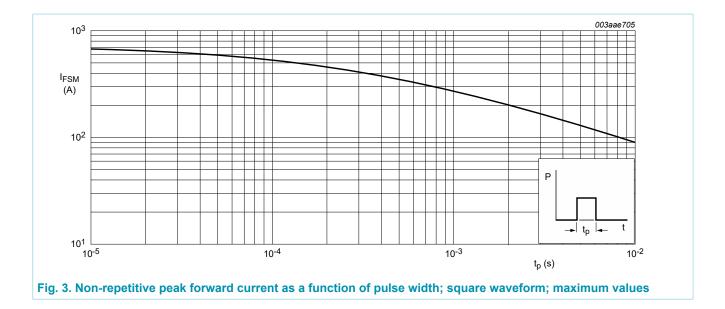


Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

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# BYV29FB-600

#### Enhanced ultrafast power diode



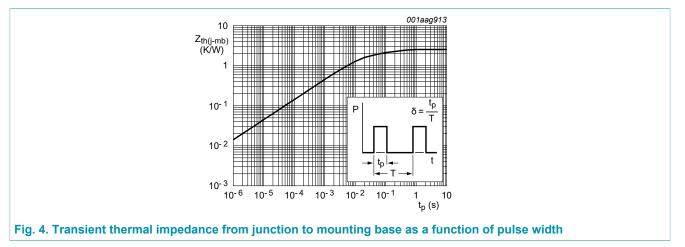
BYV29FB-600

Enhanced ultrafast power diode

#### 8. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	Fig. 4		-	-	2.5	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient free air	in free air	[1]	-	50	-	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

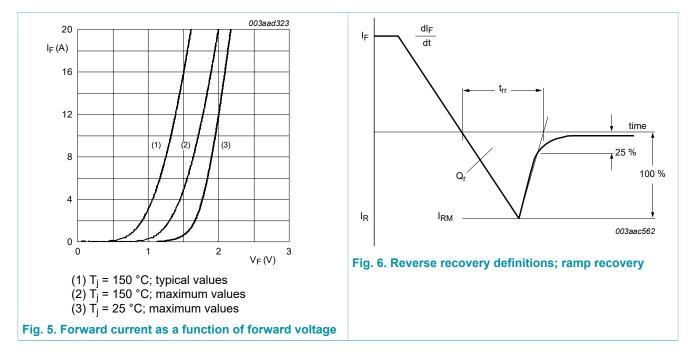


BYV29FB-600

Enhanced ultrafast power diode

#### 9. Characteristics

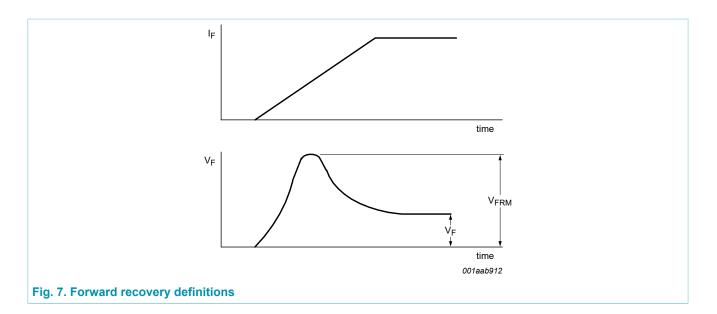
Table 6. Cha	aracteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 8 A; T <sub>j</sub> = 25 °C; <u>Fig. 5</u>	-	1.45	1.9	V
		I <sub>F</sub> = 8 A; T <sub>j</sub> = 150 °C; <u>Fig. 5</u>	-	1.25	1.7	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 600 V; T <sub>j</sub> = 100 °C	-	-	1.5	mA
		V <sub>R</sub> = 600 V; T <sub>j</sub> = 25 °C	-	-	50	μA
Dynamic ch	naracteristics	· · · · ·				
t <sub>rr</sub>	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 100 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 6$	-	17.5	35	ns
I <sub>RM</sub>	peak reverse recovery current	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}$	-	1.5	-	A
Q <sub>r</sub>	recovered charge		-	13	-	nC
$V_{\sf FR}$	forward recovery voltage	I <sub>F</sub> = 1 A; dI <sub>F</sub> /dt = 100 A/μs; <u>Fig. 7</u>	-	3.2	-	V



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# **BYV29FB-600**

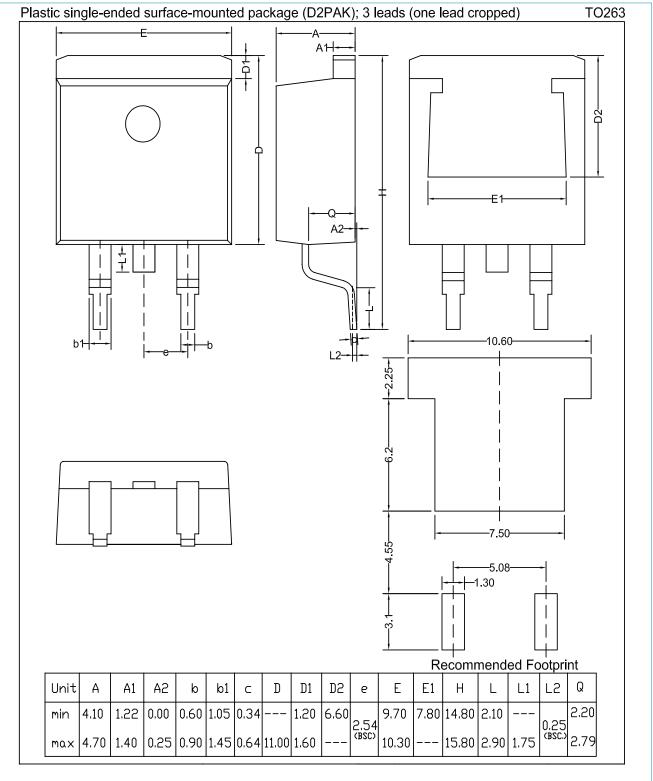
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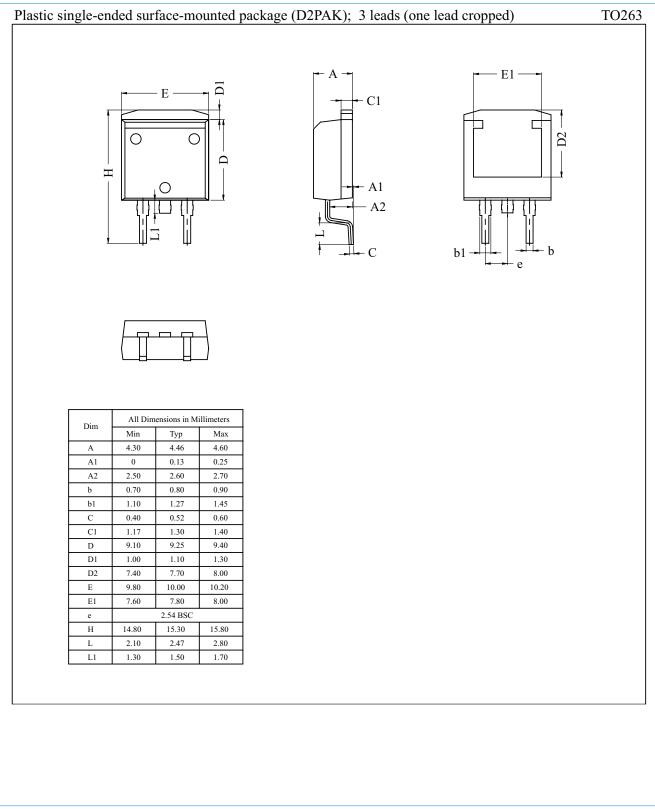
## **10. Package outline**

#### Assembly factory: N



#### Enhanced ultrafast power diode

#### Assembly factory: P



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# 11. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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